



- * **Designed to meet IEEE802.3at requirement**
- * **Lead-Free & Designed to meet RoHS requirement**
- * **Designed to meet IR 255 °C peak Requirement.**
- * **Primary inductance 350µH min. with 8mA DC Bias**
- * **Operating temperature range: -40°C to +85°C**
- * **POE applications with 720mA current capability**

Part Number	Turn Ratio (±3%)	OCL(uH Min) @ 100KHz/0.1V with 8mADC Bias	L.L (uH Max)	C _{w/w} (pF Max)	DCR (Ω Max)	Hi-Pot (V _{rms} MIN)
H2470G	1CT:1CT	350	0.5	28	0.9	AC 1500/ 1mA

Part Number	Insertion Loss 0.3~100MHZ (dB Max)	Return Loss (dB Min)				Cross Talk (dB Min)		DCMR (dB Min)		
		0.3-30MH	60MHz	80MHz	100MHz	0.3-60MHz	60-100MHz	0.3-30MHz	60MHz	100MHz
H2470G	-1.1	-18	-14	-12	-10	-42	-35	-40	-35	-30

Unless otherwise specified tolerances: xx.xo ± 0.25mm
o.xx ± 0.05mm

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